



STTA406

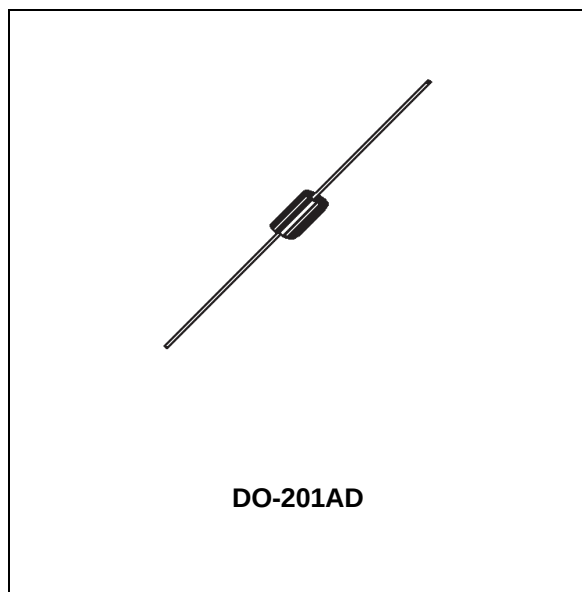
TURBOSWITCH™ ULTRA-FAST HIGH VOLTAGE DIODE

MAJOR PRODUCT CHARACTERISTICS

I_P	4 A
V_{RRM}	600 V
t_{rr} (typ.)	25 ns
V_F (max)	1.5 V

FEATURES AND BENEFITS

- SPECIFIC TO FREEWHEEL MODE OPERATIONS: FREEWHEEL OR BOOSTER DIODE
- ULTRA-FAST, AND SOFT RECOVERY
- VERY LOW OVERALL POWER LOSSES IN BOTH THE DIODE AND THE COMPANION TRANSISTOR
- HIGH FREQUENCY OPERATIONS



DO-201AD

DESCRIPTION

The TURBOSWITCH is a very high performance series of ultra-fast high voltage power diodes.

TURBOSWITCH family, drastically cuts losses in both the diode and the associated switching IGBT or MOSFET in all freewheel mode operations and

is particularly suitable and efficient in motor control freewheel applications and in booster diode applications in power factor control circuitries. Packaged in DO-201AD this 600V device is particularly intended for use on 240V domestic mains.

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		VALUE	Unit
V _{RRM}	Repetitive peak reverse voltage		600	V
I _P	Peak forward current (1)	T _{amb} = 65°C δ = 0.5	4	A
I _{FRM}	Repetitive peak forward current	t _p = 5μs F = 5kHz square	30	A
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms sinusoidal	80	A
T _j	Maximum operating junction temperature		125	°C
T _{stg}	Storage temperature range		- 40 to 150	°C

(1) square waveform and on infinite heatsink

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THERMAL DATA

Symbol	Parameter	Max.	Unit
$R_{th(j-l)}$	Junction to lead L lead = 10mm	20	°C/W
$R_{th(j-a)}$	Junction to ambient on printed circuit L lead = 10mm	75	°C/W

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions		Typ.	Max.	Unit
V_F **	Forward voltage drop	$I_F = 4\text{ A}$	$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	1.25	1.75 1.5	V V
I_R *	Reverse leakage current	$V_R = 0.8\text{ V}_{RRM}$	$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	0.75	50 2	μA mA
V_{to}	Threshold voltage	$I_p < 3 \cdot I_{F(AV)}$	$T_j = 125^\circ\text{C}$		1.15	V
R_d	Dynamic resistance				85	m Ω

Test pulse : * $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$ ** $t_p = 5\text{ ms}$, $\delta < 2\%$

To evaluate the maximum conduction losses use the following equation :

$$P = V_{to} \times I_{F(AV)} + R_d \times I_F^2(RMS)$$

DYNAMIC ELECTRICAL CHARACTERISTICS

TURN-OFF SWITCHING

Symbol	Parameter	Test conditions	Typ.	Max.	Unit
t_{rr}	Reverse recovery time	$I_F = 0.5\text{ A}$ $I_R = 1\text{ A}$ $I_{rr} = 0.25\text{ A}$	25		ns
		$I_F = 1\text{ A}$ $di/dt = -50\text{ A}/\mu\text{s}$ $V_R = 30\text{ V}$		55	ns

TURN-ON SWITCHING

Symbol	Parameter	Test conditions	Typ.	Max.	Unit
t_{fr}	Forward recovery time	$I_F = 4\text{ A}$ $dI_F/dt = 100\text{ A}/\mu\text{s}$ Measured at $1.1 \times V_F$ max. $T_j = 25^\circ\text{C}$		200	ns
V_{FP}	Peak forward voltage			20	V

Fig. 1: Power dissipation versus average forward current.

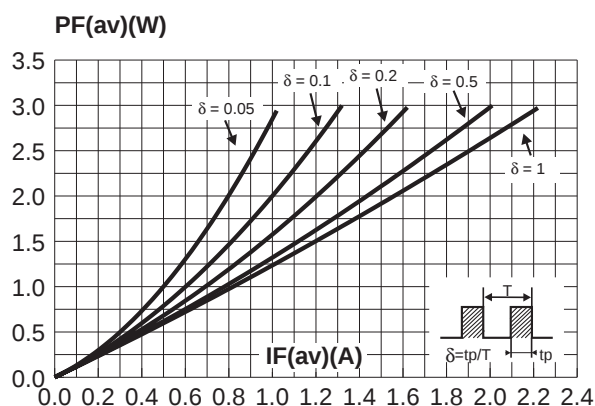


Fig. 2: Average forward current versus ambient temperature ($\delta=0.5$).

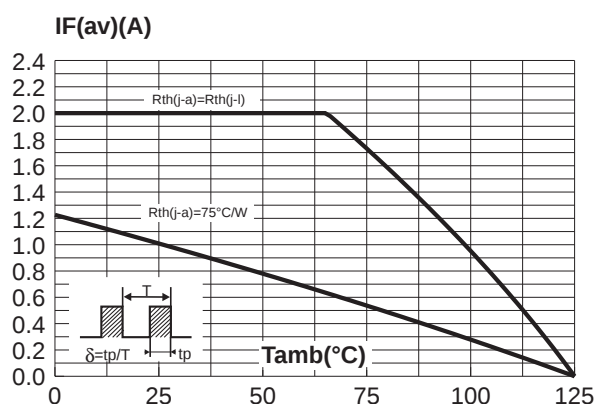


Fig. 3: Relative variation of thermal impedance junction to ambient versus pulse duration (epoxy printed circuit board, $e(\text{Cu})=35\mu\text{m}$), recommended pad layout).

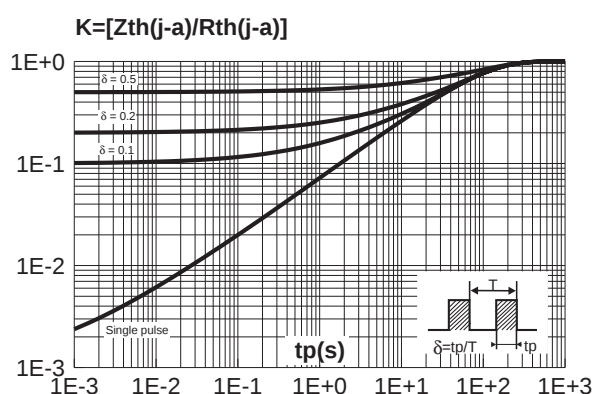


Fig 4-2 : Forward voltage drop versus forward current (high level).

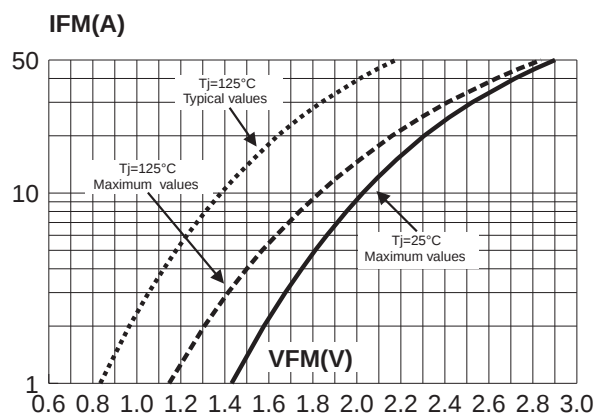


Fig. 4-1: Forward voltage drop versus forward current (low level).

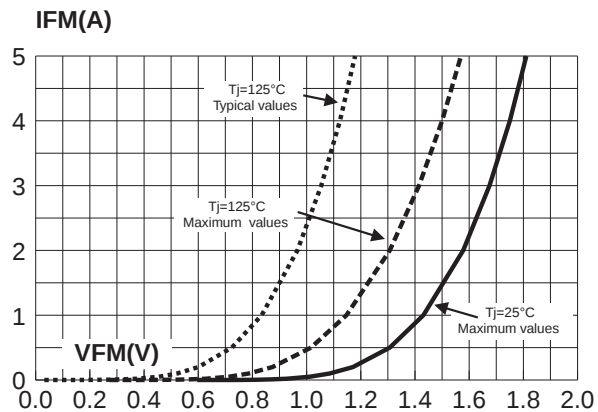


Fig 5 : Reverse recovery time versus dI_F/dt .

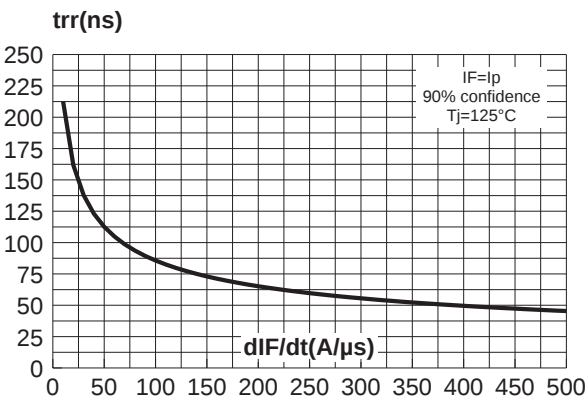


Fig. 6: Reverse recovery current versus dI_F/dt .

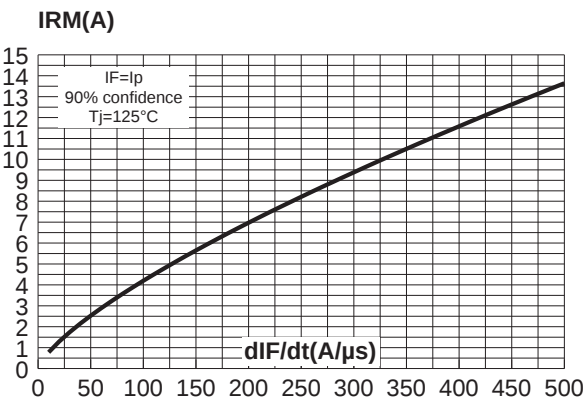


Fig. 7: Transient peak forward voltage versus dI_F/dt .

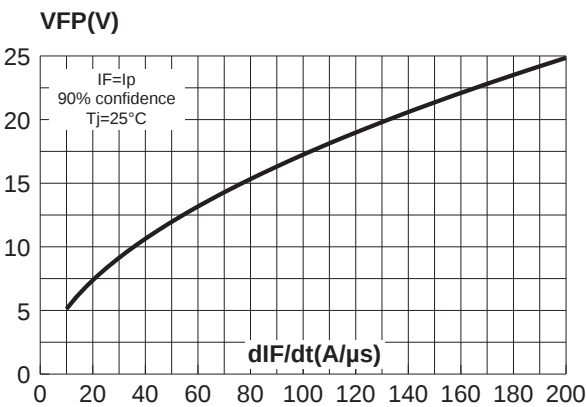


Fig. 9: Junction capacitance versus reverse voltage applied (typical values).

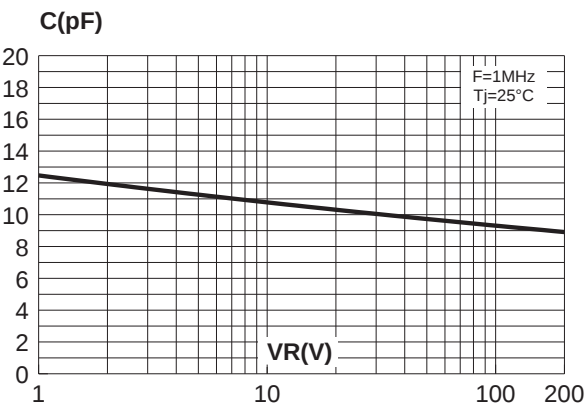
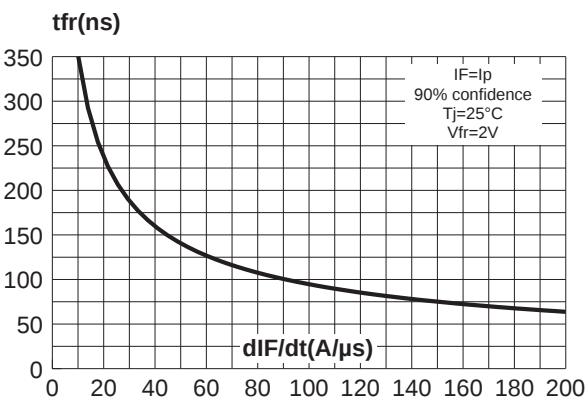
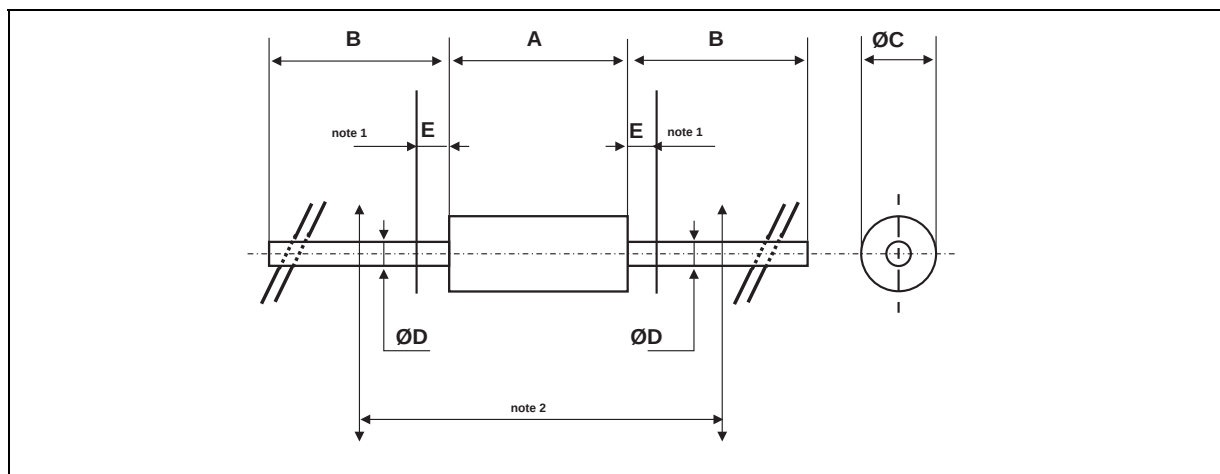


Fig. 8: Forward recovery time versus dI_F/dt .



PACKAGE MECHANICAL DATA
DO-201AD


REF.	DIMENSIONS				NOTES
	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
A		9.50		0.374	1 - The lead diameter Ø D is not controlled over zone E 2 - The minimum axial length within which the device may be placed with its leads bent at right angles is 0.59"(15 mm)
B	25.40		1.000		
Ø C		5.30		0.209	
Ø D		1.30		0.051	
E		1.25		0.049	

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STTA406	STTA406	DO-201AD	1.166g	600	Ammopack
STTA406RL	STTA406	DO-201AD	1.166g	1900	Tape & reel

- Cooling method: by convection (method A)
- Band indicated cathode
- Epoxy meets UL94,V0

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